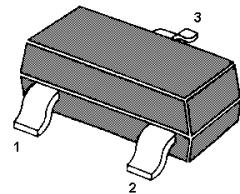
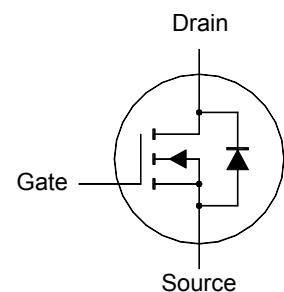


MMFTN123A

N-Channel Logic Level Enhancement Mode Field Effect Transistor



1. Gate 2. Source 3. Drain
TO-236 Plastic Package



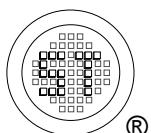
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	100	V
Gate-Source Voltage	V_{GSS}	± 20	V
Drain Current	I_D	190	mA
Peak Drain Current	I_{DM}	770	mA
Total Power Dissipation	P_{tot}	500	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction to Ambient ¹⁾	R_{thj-a}	250	K/W

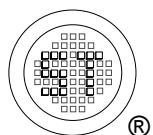
¹⁾ Device mounted on a printed-circuit board.



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Characteristics at $T_a = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage at $I_D = 250 \mu\text{A}$	$V_{(\text{BR})\text{DSS}}$	100	-	-	V
Gate-Source Threshold Voltage at $V_{GS} = V_{DS}$, $I_D = 1 \text{ mA}$	$V_{G\text{Sth}}$	0.8	-	1.8	V
Drain-Source Leakage Current at $V_{DS} = 100 \text{ V}$	I_{DSS}	-	-	1	μA
Gate-Source Leakage Current at $V_{GS} = \pm 20 \text{ V}$	I_{GSS}	-	-	± 50	nA
Drain-Source On-State Resistance at $V_{GS} = 10 \text{ V}$, $I_D = 190 \text{ mA}$ at $V_{GS} = 4.5 \text{ V}$, $I_D = 150 \text{ mA}$	$R_{\text{DS}(\text{ON})}$	- -	- -	6 10	Ω
Input Capacitance at $V_{DS} = 25 \text{ V}$, $f = 1 \text{ MHz}$	C_{iss}	-	-	20.9	pF
Output Capacitance at $V_{DS} = 25 \text{ V}$, $f = 1 \text{ MHz}$	C_{oss}	-	-	4.5	pF
Reverse Transfer Capacitance at $V_{DS} = 25 \text{ V}$, $f = 1 \text{ MHz}$	C_{rss}	-	-	3.1	pF
Turn-On Delay Time at $V_{DD} = 50 \text{ V}$, $I_D = 190 \text{ mA}$, $V_{GS} = 10 \text{ V}$, $R_G = 6 \Omega$	$t_{d(\text{on})}$	-	-	3.5	ns
Turn-On Rise Time at $V_{DD} = 50 \text{ V}$, $I_D = 190 \text{ mA}$, $V_{GS} = 10 \text{ V}$, $R_G = 6 \Omega$	t_r	-	-	4.6	ns
Turn-Off Delay Time at $V_{DD} = 50 \text{ V}$, $I_D = 190 \text{ mA}$, $V_{GS} = 10 \text{ V}$, $R_G = 6 \Omega$	$t_{d(\text{off})}$	-	-	11.1	ns
Turn-Off Fall Time at $V_{DD} = 50 \text{ V}$, $I_D = 190 \text{ mA}$, $V_{GS} = 10 \text{ V}$, $R_G = 6 \Omega$	t_f	-	-	33	ns



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